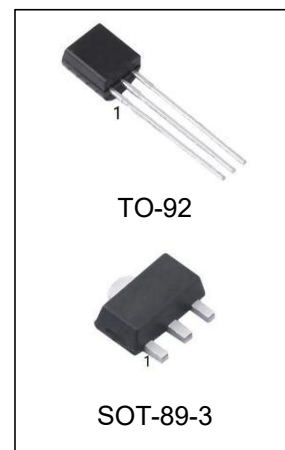


3-TERMINAL 0.1A NEGATIVE VOLTAGE REGULATOR

DESCRIPTION

This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power-pass elements to make high current voltage regulators.

Each of these regulators can deliver up to 100mA of output current. The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload. When used as a replacement for a zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.



FEATURES

- Output Current Up to 100mA
- No External Components
- Internal Thermal Overload Protection
- Internal Short-Circuit Limiting
- Output Voltage of -5V, -6V, -8V, -9V, -12V, -15V, -18V and -24V.
- Moisture Sensitivity Level 3

ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
LM79L05Z	TO-92	79L05	BAG	1000pcs/box
LM79L06Z	TO-92	79L06	BAG	1000pcs/box
LM79L08Z	TO-92	79L08	BAG	1000pcs/box
LM79L09Z	TO-92	79L09	BAG	1000pcs/box
LM79L12Z	TO-92	79L12	BAG	1000pcs/box
LM79L15Z	TO-92	79L15	BAG	1000pcs/box
LM79L18Z	TO-92	79L18	BAG	1000pcs/box
LM79L24Z	TO-92	79L24	BAG	1000pcs/box
LM79L05MK/TR	SOT-89-3	79L05,79L05F,QMAA	REEL	1000pcs/reel
LM79L06MK/TR	SOT-89-3	79L06,79L06F	REEL	1000pcs/reel
LM79L08MK/TR	SOT-89-3	79L08,79L08F	REEL	1000pcs/reel
LM79L09MK/TR	SOT-89-3	79L09,79L09F	REEL	1000pcs/reel
LM79L12MK/TR	SOT-89-3	79L12,79L12F	REEL	1000pcs/reel
LM79L15MK/TR	SOT-89-3	79L15,79L15F	REEL	1000pcs/reel
LM79L18MK/TR	SOT-89-3	79L18,79L18F	REEL	1000pcs/reel
LM79L24MK/TR	SOT-89-3	79L24,79L24F	REEL	1000pcs/reel

ABSOLUTE MAXIMUM RATINGS

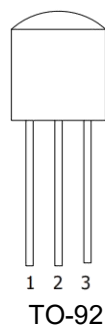
CHARACTERISTIC		SYMBOL	MIN.	MAX.	UNIT
Input Voltage	LM79L05 ~ LM79L09	VIN	-	-30	V
	LM79L12 ~ LM79L18		-	-35	
	LM79L24		-	-40	
Maximum Power Dissipation at T _A = 25°C / TO-92		PDMax	-	0.770	W
Thermal Resistance Junction-To-Ambient / TO-92		θJA	-	162	°C/W
Lead Temperature (Soldering, 10 sec)		TSOL	-	260	°C
Storage Temperature Range		TSTG	-65	150	°C
Operating Junction Temperature Range		TJOPR	0	150	°C

Note: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC		SYMBOL	MIN.	MAX.	UNIT
Input Voltage	LM79L05	VIN	-7	-20	V
	LM79L06		-8	-20	
	LM79L08		-10.5	-23	
	LM79L09		-11.5	-24	
	LM79L12		-14.5	-27	
	LM79L15		-17.5	-30	
	LM79L18		-20.5	-33	
	LM79L24		-27	-38	
Output Current		I _o	-	100	mA
Operating Virtual Junction Temperature		T _J	0	125	°C

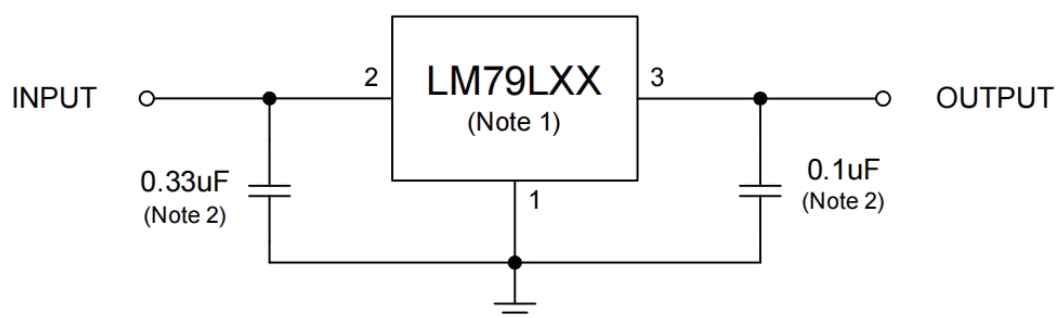
PIN CONFIGURATION



PIN DESCRIPTION

Pin No.	TO-92 / SOT89-3 LEAD	
	Name	Function
1	GND	Ground
2	VIN	Input Voltage
3	VOUT	Output Voltage

TYPICAL APPLICATION



Note 1. To specify an output voltage, substitute voltage for "XX".

Note 2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.

ELECTRICAL CHARACTERISTICS

LM79L05 (At specified virtual junction temperature, $V_{IN} = -10V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V_{OUT}		25°C	-4.8	-5	-5.2	V
		$1mA \leq I_o \leq 40mA$ $-7V \leq V_{IN} \leq 20V$	0°C ~125°C	-4.75	-5	-5.25	
		$1mA \leq I_o \leq 70mA$		-4.75	-5	-5.25	
Line Regulation	ΔV_{LINE}	$-7V \leq V_{IN} \leq -20V$	25°C		32	150	mV
		$-8V \leq V_{IN} \leq -20V$			26	100	
Load Regulation	ΔV_{LOAD}	$1mA \leq I_o \leq 100mA$	25°C		15	60	mV
		$1mA \leq I_o \leq 40mA$			8	30	
Bias Current	I_B		25°C		3.8	6	mA
			125°C			5.5	
Bias Current Change	ΔI_B	$-8V \leq V_{IN} \leq -20V$	0°C ~125°C			1.5	mA
		$1mA \leq I_o \leq 40mA$				0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		42		uV
Ripple Rejection	RR	$-8V \leq V_{IN} \leq -18V$, $f=120Hz$	25°C	41	49		dB
Dropout Voltage	V_D		25°C		1.7		V

LM79L06 (At specified virtual junction temperature, $V_{IN} = -11V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V_{OUT}		25°C	-5.76	-6	-6.24	V
		$1mA \leq I_o \leq 40mA$ $-8V \leq V_{IN} \leq -21V$	0°C ~125°C	-5.7	-6	-6.3	
		$1mA \leq I_o \leq 70mA$		-5.7	-6	-6.3	
Line Regulation	ΔV_{LINE}	$-8V \leq V_{IN} \leq -21V$	25°C		50	150	mV
		$-9V \leq V_{IN} \leq -21V$			45	110	
Load Regulation	ΔV_{LOAD}	$1mA \leq I_o \leq 100mA$	25°C		12	70	mV
		$1mA \leq I_o \leq 40mA$			5.5	35	
Bias Current	I_B		25°C			6	mA
			125°C			5.5	
Bias Current Change	ΔI_B	$-9V \leq V_{IN} \leq -21V$	0°C ~125°C			1.5	mA
		$1mA \leq I_o \leq 40mA$				0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		50		uV
Ripple Rejection	RR	$-9V \leq V_{IN} \leq -19V$, $f=120Hz$	25°C	39	47		dB
Dropout Voltage	V_D		25°C		1.7		V

LM79L08 (At specified virtual junction temperature, $V_{IN} = -14V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V _{OUT}		25°C	-7.7	-8	-8.3	V
		1mA ≤ I _o ≤ 40mA -10.5V ≤ V _{IN} ≤ -23V	0°C ~125°C	-7.6	-8	-8.4	
		1mA ≤ I _o ≤ 70mA		-7.6	-8	-8.4	
Line Regulation	ΔV _{LINE}	-10.5V ≤ V _{IN} ≤ -23V	25°C		20	175	mV
		-11V ≤ V _{IN} ≤ -23V			12	125	
Load Regulation	ΔV _{LOAD}	1mA ≤ I _o ≤ 100mA	25°C		18	80	mV
		1mA ≤ I _o ≤ 40mA			9	42	
Bias Current	I _B		25°C			6.5	mA
			125°C			6	
Bias Current Change	ΔI _B	-11V ≤ V _{IN} ≤ -23V	0°C ~125°C			1.5	mA
		1mA ≤ I _o ≤ 40mA				0.1	
Output Noise Voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		60		μV
Ripple Rejection	RR	-12V ≤ V _{IN} ≤ -23V, f=120Hz	25°C	42	49		dB
Dropout Voltage	V _D		25°C		1.7		V

LM79L09 (At specified virtual junction temperature, $V_{IN} = -15V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V _{OUT}		25°C	-8.64	-9	-9.36	V
		1mA ≤ I _o ≤ 40mA -11V ≤ V _{IN} ≤ -24V	0°C ~125°C	-8.55	9	-9.45	
		1mA ≤ I _o ≤ 70mA		-8.55	9	-9.45	
Line Regulation	ΔV _{LINE}	-11V ≤ V _{IN} ≤ -24V	25°C		80	200	mV
		-12V ≤ V _{IN} ≤ -24V			20	160	
Load Regulation	ΔV _{LOAD}	1mA ≤ I _o ≤ 100mA	25°C		17	90	mV
		1mA ≤ I _o ≤ 40mA			8	45	
Bias Current	I _B		25°C		3.8	6.5	mA
			125°C			6	
Bias Current Change	ΔI _B	-12V ≤ V _{IN} ≤ -24V	0°C ~125°C			1.5	mA
		1mA ≤ I _o ≤ 40mA				0.1	
Output Noise Voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		64		μV
Ripple Rejection	RR	-8V ≤ V _{IN} ≤ -18V, f=120Hz	25°C	35	43		dB
Dropout Voltage	V _D		25°C		1.7		V

LM79L12 (At specified virtual junction temperature, $V_{IN} = -19V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V_{OUT}		25°C	-11.5	-12	-12.5	V
		$1mA \leq I_o \leq 40mA$ $-14.5V \leq V_{IN} \leq -27V$	0°C ~125°C	-11.4	-12	-12.6	
		$1mA \leq I_o \leq 70mA$		-11.4	-12	-12.6	
Line Regulation	ΔV_{LINE}	$-14.5V \leq V_{IN} \leq -27V$	25°C		50	250	mV
		$-16V \leq V_{IN} \leq -27V$			40	200	
Load Regulation	ΔV_{LOAD}	$1mA \leq I_o \leq 100mA$	25°C		24	100	mV
		$1mA \leq I_o \leq 40mA$			15	50	
Bias Current	I_B		25°C			6.5	mA
			125°C			6	
Bias Current Change	ΔI_B	$-16V \leq V_{IN} \leq -27V$	0°C ~125°C			1.5	mA
		$1mA \leq I_o \leq 40mA$				0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		70		uV
Ripple Rejection	RR	$-15V \leq V_{IN} \leq -25V, f=120Hz$	25°C	37	42		dB
Dropout Voltage	V_D		25°C		1.7		V

LM79L15 (At specified virtual junction temperature, $V_{IN} = -23V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V_{OUT}		25°C	-14.4	-15	-15.6	V
		$1mA \leq I_o \leq 40mA$ $-17.5V \leq V_{IN} \leq -30V$	0°C ~125°C	-14.25	-15	-15.75	
		$1mA \leq I_o \leq 70mA$		-14.25	-15	-15.75	
Line Regulation	ΔV_{LINE}	$-17.5V \leq V_{IN} \leq -30V$	25°C		65	300	mV
		$-27V \leq V_{IN} \leq -30V$			58	250	
Load Regulation	ΔV_{LOAD}	$1mA \leq I_o \leq 100mA$	25°C		25	150	mV
		$1mA \leq I_o \leq 40mA$			15	75	
Bias Current	I_B		25°C		4.2	6.5	mA
			125°C			6	
Bias Current Change	ΔI_B	$-20V \leq V_{IN} \leq -30V$	0°C ~125°C			1.5	mA
		$1mA \leq I_o \leq 40mA$				0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		82		uV
Ripple Rejection	RR	$-18.5V \leq V_{IN} \leq -28.5V$, $f=120Hz$	25°C	37	44		dB
Dropout Voltage	V_D		25°C		1.7		V

LM79L18 (At specified virtual junction temperature, $V_{IN} = -26V$, $I_o = 40mA$ (Unless otherwise noted))

PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V_{OUT}		25°C	-17.3	-18	-18.7	V
		$1mA \leq I_o \leq 40mA$ $-20.5V \leq V_{IN} \leq -33V$	0°C ~125°C	-17.1	-18	-18.9	
		$1mA \leq I_o \leq 70mA$		-17.1	-18	-18.9	
Line Regulation	ΔV_{LINE}	$-20.7V \leq V_{IN} \leq -33V$	25°C		70	360	mV
		$-21V \leq V_{IN} \leq -33V$			64	300	
Load Regulation	ΔV_{LOAD}	$1mA \leq I_o \leq 100mA$	25°C		27	180	mV
		$1mA \leq I_o \leq 40mA$			19	90	
Bias Current	I_B		25°C		4.7	6.5	mA
			125°C			6	
Bias Current Change	ΔI_B	$-21V \leq V_{IN} \leq -33V$	0°C ~125°C			1.5	mA
		$1mA \leq I_o \leq 40mA$				0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		82		uV
Ripple Rejection	RR	$-23V \leq V_{IN} \leq -33V, f=120Hz$	25°C	32	36		dB
Dropout Voltage	V_D		25°C		1.7		V

LM79L24 (At specified virtual junction temperature, $V_{IN} = -32V$, $I_o = 40mA$ (Unless otherwise noted))

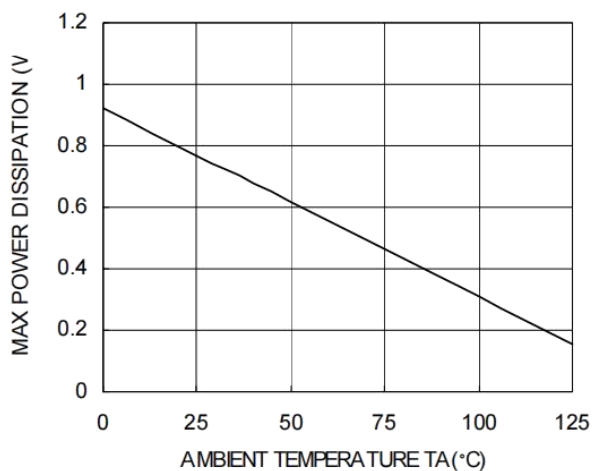
PARAMETER	SYMBOL	TEST CONDITION ^(Note 1)		MIN.	TYP.	MAX.	UNIT
Output Voltage ^(Note 2)	V_{OUT}		25°C	-23	-24	-25	V
		$1mA \leq I_o \leq 40mA$ $-27V \leq V_{IN} \leq -38V$	0°C ~125°C	-22.8	-24	-25.2	
		$1mA \leq I_o \leq 70mA$		-22.8	-24	-25.2	
Line Regulation	ΔV_{LINE}	$-27V \leq V_{IN} \leq -38V$	25°C		95	480	mV
		$-28V \leq V_{IN} \leq -38V$			78	400	
Load Regulation	ΔV_{LOAD}	$1mA \leq I_o \leq 100mA$	25°C		41	240	mV
		$1mA \leq I_o \leq 40mA$			28	120	
Bias Current	I_B		25°C		4.8	6.5	mA
			125°C			6	
Bias Current Change	ΔI_B	$-21V \leq V_{IN} \leq -38V$	0°C ~125°C			1.5	mA
		$1mA \leq I_o \leq 40mA$				0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		82		uV
Ripple Rejection	RR	$-29V \leq V_{IN} \leq -35V, f=120Hz$	25°C	30	33		dB
Dropout Voltage	V_D		25°C		1.7		V

Note 1. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

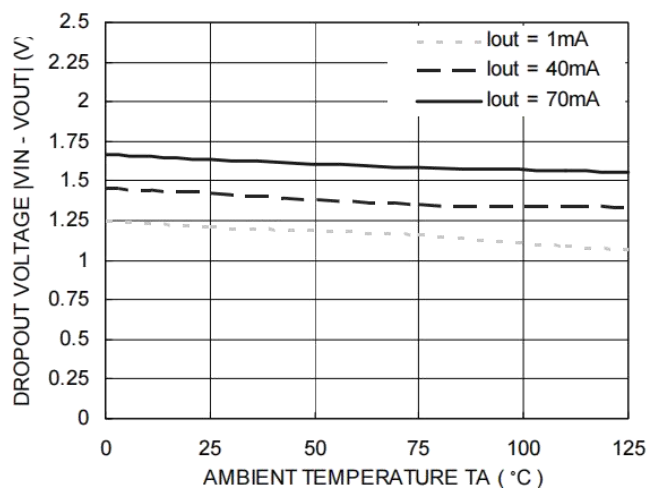
All characteristics are measured with a 0.33uF capacitor across the input and a 0.1uF capacitor across the output.

Note 2. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

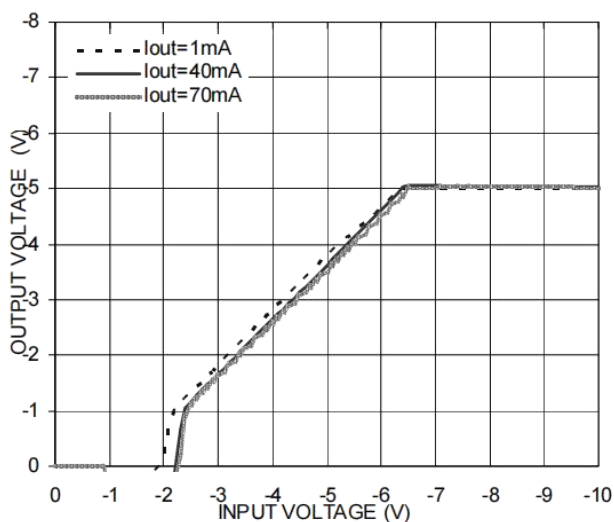
TYPICAL OPERATING CHARACTERISTICS



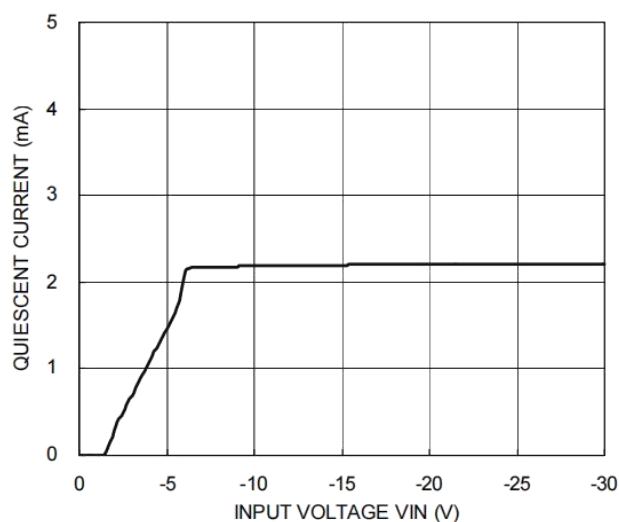
Power Dissipation vs. Ambient Temperature, TO-92



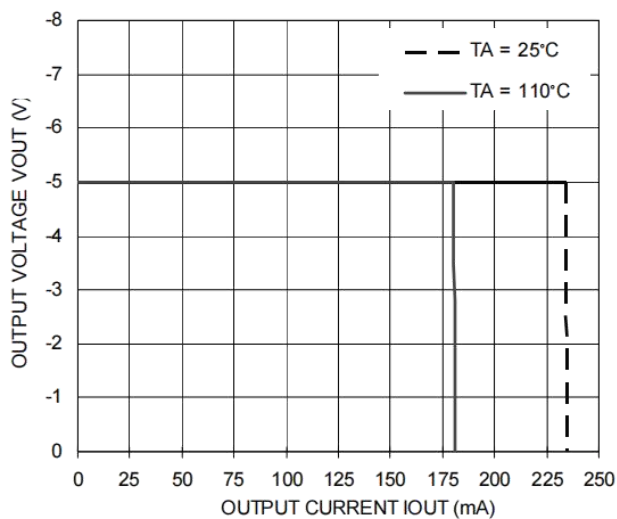
Dropout Voltage vs. Ambient Temperature



Output Voltage vs. Input Voltage



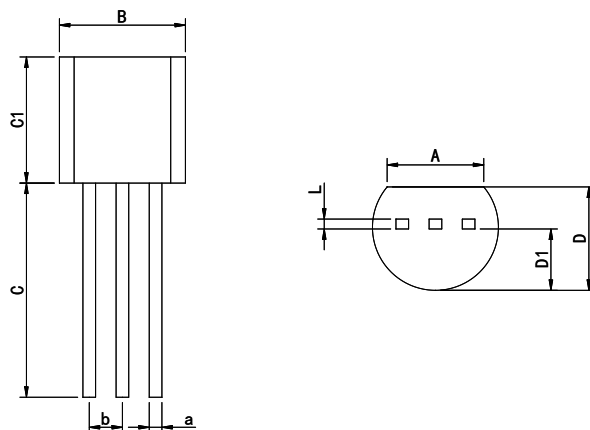
Quiescent Current vs. Input Voltage



Output Voltage vs. Output Current

封装外型尺寸

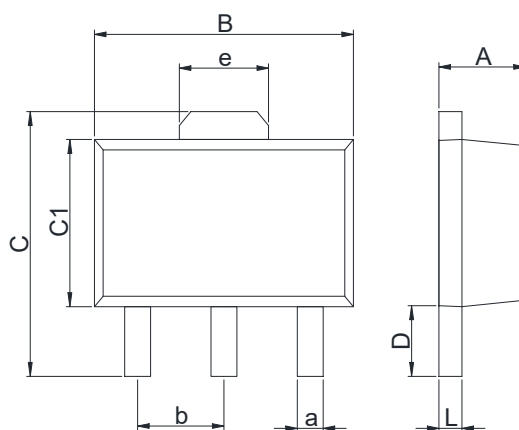
TO-92



Dimensions In Millimeters(TO-92)

Symbol:	A	B	C	C1	D	D1	L	a	b
Min:	3.43	4.44	13.5	4.32	3.17	2.03	0.33	0.40	1.27BSC
Max:	4.13	5.21	15.3	5.34	4.19	2.67	0.42	0.52	

SOT89-3



Dimensions In Millimeters(SOT89-3)

Symbol:	A	B	C	C1	D	L	a	b	e
Min:	1.40	4.40	3.94	2.30	0.90	0.35	0.40	1.50	1.55
Max:	1.60	4.60	4.25	2.60	1.20	0.44	0.55	BSC	BSC

Revision History

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2014-8	New	1-11
V1.1	2018-10	Modify the package dimension diagram SOT-89-3、 Update Package Type	1、 9
V1.2	2024-11	Add model LM79L05MK Marking、 Update Lead Temperature	1、 2
V1.3	2025-12	Update important statements	11

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